
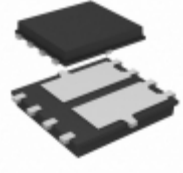
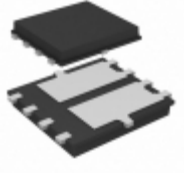

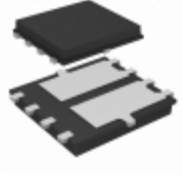
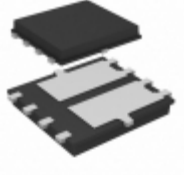
	<h2>SI7905DN-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7905DN-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 40V 6A PPAK 1212-8</p> <p>Datenblätter:  SI7905DN-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 25500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7905DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 40V 6A PPAK 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	25500 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	20.8W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	60 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	880pF @ 20V
Verpackung	Tape & Reel (TR)















SI7905DN-T1-GE3 ist neu im Original, Suche SI7905DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7905DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7905DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7905DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 40V 6A 1212-8</p>	 <p>SI7909DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 12V 5.3A 1212-8</p>	 <p>SI7905DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 40V 6A PPAK 1212-8</p>	 <p>SI7904DN.. V V QFN8</p>
 <p>SI7909DN-T1-E3 Vishay / Siliconix MOSFET 2P-CH 12V 5.3A 1212-8</p>	 <p>SI7905DN-T1-E3 Vishay / Siliconix MOSFET 2P-CH 40V 6A 1212-8</p>	 <p>SI7904DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 5.3A 1212-8</p>	 <p>SI7909DN-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 12V 5.3A 1212-8</p>

heiße Teile

Mehr

 SI7900ADN	 SI7900AEDN	 SI7900AEDN-T1	 SI7900AEDN-T1-E3	 SI7900AEDN-T1-E3
 SI7900AEDN-T1-GE3	 SI7900AEDN-T1-GE3	 SI7900EDN	 SI7900EDN-T1	 SI7900EDN-T1-E3
 SI7900EDN-T1-GE3	 SI7901EDN-T1	 SI7901EDN-T1-E3	 SI7901EDN-T1-E3	 SI7904BDN-T1-E3
 SI7904BDN-T1-E3	 SI7904BDN-T1-GE3	 SI7904BDN-T1-GE3	 SI7904DN	 SI7904DN-T1
 SI7904DN-T1-E3	 SI7904DN-T1-E3	 SI7904DN-T1-GE3	 SI7904DN-T1-GE3	 SI7905DN-T1-GE3
 SI7909DN-T1-E3	 SI7909DN-T1-E3	 SI7909DN-T1-GE3	 SI7909DN-T1-GE3	 SI7911DN
 SI7911DN-T1-E3	 SI7911DN-T1-E3	 SI7911DN-T1-GE3	 SI7911DN-T1-GE3	 SI7913DN-T1-E3
 SI7913DN-T1-E3	 SI7913DN-T1-GE3	 SI7913DN-T1-GE3	 SI7922DN-T1-E3	 SI7922DN-T1-E3
 SI7922DN-T1-GE3	 SI7922DN-T1-GE3	 SI7923DN-T1-E3	 SI7923DN-T1-E3	 SI7923DN-T1-GE3
 SI7923DN-T1-GE3	 SI7938DP-T1-GE3	 SI7938DP-T1-GE3	 SI7940DP	 SI7940DP-T1-E3

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